

465V NPN HIGH VOLTAGE POWER TRANSISTOR

Features

- BV_{CEO} > 465V
- BV_{CES} > 800V
- BV_{EBO} > 9V
- I_C = 1.5A high Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

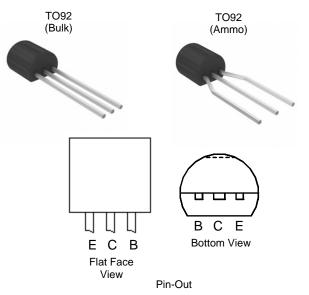
Applications

Low power AC-DC SMPS for:

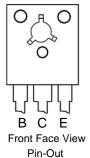
- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED lighting

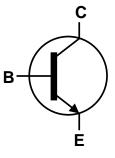
Mechanical Data

- Case: TO92 or TO126
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 ³
- Weight: TO92: 200mg (Approximate)
 TO126: 400mg (Approximate)









Device Schematic

Ordering Information (Note 4)

Product	Package	Marking	Quantity	
APT13003HZ-G1	TO92 (Straight Legs)	13003HZ-G1	10,000 Bulk, Loose per Box	
APT13003HZTR-G1	TO92 (Joggled Legs)	13003HZ-G1	2,000 Taped, per Ammo Box	
APT13003HU-G1	TO126	GU13003H	4,000 Bulk, Loose per Box	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





= Manufacturers' code marking
For TO92: 13003HZ-G1= Product Type Marking ID
For TO126: GU13003H = Product Type Marking ID
YWW = Date Code Marking
e.g. 312 = Year 2013, Week 12.

8 = Assembly site code XX = Batch Number



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	800	V
Collector-Emitter Voltage	V _{CEO}	465	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	Ic	1.5	А
Peak Pulse Collector Current(Note 5)	I _{CM}	3	Α
Continuous Base Current	I _B	0.75	A
Peak Pulse Base Current (Note 5)	I _{BM}	1.5	A

Note:

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

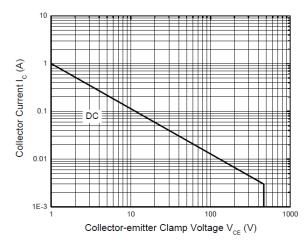
Characteristic		Symbol	Value	Unit	
Dower Discipation	For TO92	0	1.1	101	
Power Dissipation	For TO126 @ T _C = +25°C	TO126 @ T _C = +25°C		W	
Thormal Basistanas, Jungtian to Ambient Air	For TO92	D	113.6	°C/W	
Thermal Resistance, Junction to Ambient Air	For TO126	$R_{\theta JA}$	96	C/VV	
Thermal Resistance, Junction to Case	For TO92	D	83.3	°C/W	
mermai Resistance, Junction to Case	For TO126	$R_{ heta JC}$	6.25		
Operating and Storage Temperature Range	_	T_{J} , T_{STG}	-65 to +150	°C	

ESD Ratings (Note 6)

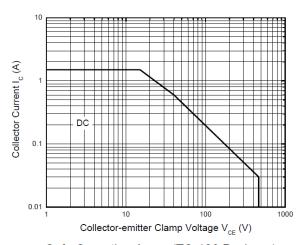
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Note:

Safe Operating Area and Derating Information (@TA = +25°C, unless otherwise specified.)



Safe Operating Areas (TO-92 Package)



Safe Operating Areas (TO-126 Package)

^{5.} Pulse test for pulse width < 5ms, duty cycle ≤ 10%.

 $^{{\}small 6.}\ \ Refer\ to\ JEDEC\ specification\ JESD22-A114\ and\ JESD22-A115.$



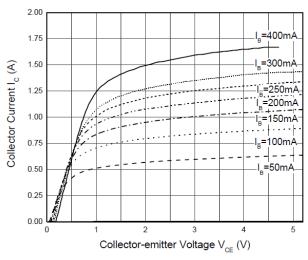
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Voltage	BV _{CES}	800	_	_	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	465	_	_	V	$I_C = 100 \mu A$
Emitter-Base Breakdown Voltage	BV _{EBO}	9	_	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	I _{CEV}			10	μA	$V_{CE} = 800V, V_{BE} = -1.5V$
DC current transfer Static ratio (Note 7)	h _{FE}	15 13 5	_ 17 _	— 30 25	_ _ _	$I_C = 0.3A$, $V_{CE} = 2V$ $I_C = 0.5A$, $V_{CE} = 2V$ $I_C = 1.0A$, $V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	0.17 0.29	0.3 0.4	V	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.25A$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}		1 1	1.0 1.2	٧	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.25A$
Output Capacitance	C _{ob}	_	16	_	pF	V _{CB} = 10V, f = 0.1MHz
Transition Frequency	f _T	4	_	_	MHz	I _C = 0.1A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}		0.3	1		
Storage Time with Resistive Load	ts	_	1.8	3	μs	$I_C = 1A, V_{CC} = 125V, I_{B1} = 0.2A,$ $I_{B2} = -0.2A, t_D = 25\mu s$
Fall Time with Resistive Load	t _f	_	0.28	0.4		1820.2Λ, τρ - 20μs

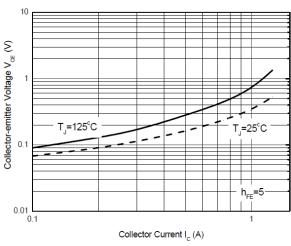
Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



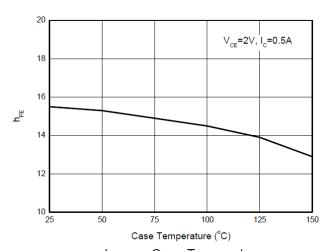
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



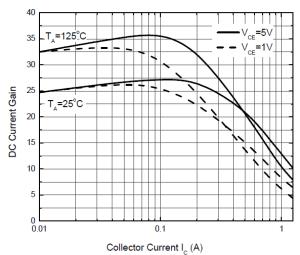
Static Characteristics



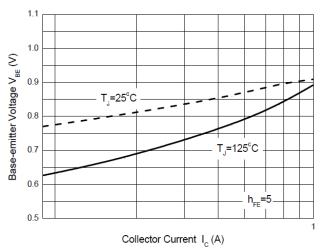
Collector-emitter Saturation Voltage



h_{FE} vs. Case Temperature



DC Current Gain vs. Collector Current



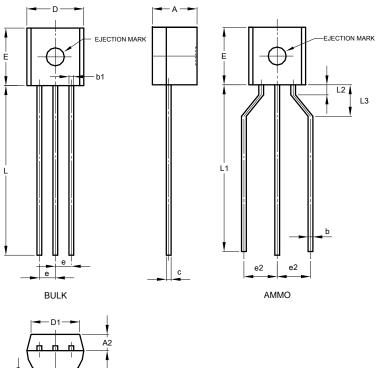
Base-emitter Saturation Voltage



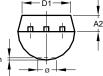
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

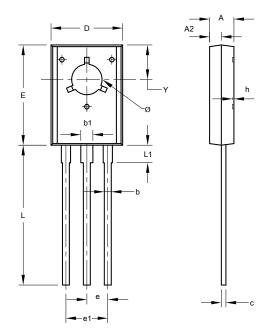
TO92 Type C



TO92 Type C					
Dim	Min Max		Тур		
Α	3.30	3.70	-		
A2	1.10	1.40	-		
b	0.38	0.55	-		
C	0.36	0.51	-		
D	4.40	4.70	-		
D1	3.430	-	-		
Е	4.30	4.70	-		
е	-	-	1.27		
e2	2.440	2.640	-		
h	0.00	0.38	-		
L	14.10	14.50	-		
L1	12.50	14.50	-		
L3	2.50	3.50	-		
Ø	-	1.60	-		
All Dimensions in mm					



TO126



TO126					
Dim	Min	Тур			
Α	2.400	2.900	-		
A2	1.060	1.500	-		
b	0.660	0.860	-		
b1	1.170	1.470	-		
C	0.400	0.600	-		
D	7.400	8.200	-		
Е	10.60	11.20	-		
е	-	-	2.280		
e1	-	-	4.560		
h	0.00	0.30	-		
L	14.50	15.90	-		
L1	1.700	2.100	-		
Υ	3.600	3.900	-		
Ø	3.100	3.550	-		
All Dimensions in mm					

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals. Note:



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